

**For Scintillation Counting, Fast Time Response
51 mm (2 inch) Diameter, Bialkali Photocathode, 8-stage, Head-on Type**

SPECIFICATIONS

GENERAL

Parameter		Description / Value	Unit
Spectral Response		300 to 650	nm
Wavelength of Maximum Response		420	nm
Window Material		Borosilicate glass	—
Photocathode	Material	Bialkali	—
	Minimum Effective Area	φ46	mm
Dynode	Structure	Linear focused	—
	Number of Stages	8	—
Base		JEDEC No. B20-102 / Flying lead type	—
Operating Ambient Temperature		-30 to +50	°C
Storage Temperature		-80 to +50	°C
Suitable Socket		E678-20B (supplied)	—

MAXIMUM RATINGS (Absolute Maximum Values)

Parameter		Value	Unit
Supply Voltage	Between Anode and Cathode	1750	V
Average Anode Current		0.1	mA

CHARACTERISTICS (at 25 °C)

Parameter		Min.	Typ.	Max.	Unit
Cathode Sensitivity	Luminous (2856 K)	70	95	—	μA/lm
	Blue Sensitivity Index (CS 5-58)	9	11	—	—
Anode Sensitivity	Luminous (2856 K)	10	47.5	—	A/lm
Gain		—	5.0 × 10 ⁵	—	—
Anode Dark Current (After 30 minute storage in darkness)		—	15	100	nA
Time Response	Anode Pulse Rise Time	—	1.8	—	ns
	Electron Transit Time	—	20	—	ns
	Transit Time Spread (FWHM)	—	250	—	ps
Pulse Linearity (±2 % deviation)		—	50	—	mA

NOTE: Anode characteristics are measured with a voltage distribution ratio and supply voltage shown below.

VOLTAGE DISTRIBUTION RATIO AND SUPPLY VOLTAGE

Electrodes	K	G	Dy1	Dy2	Dy3	Dy4	Dy5	Dy6	Dy7 (Acc)	Dy8	P
Ratio	1.3	4.8	1.5	1.5	1	1	1	1	1	1	1

Supply Voltage: 1500 V, K: Cathode, Dy: Dynode, P: Anode, G: Grid,
Acc to be connected to Dy7 with a protection resistor (R11) in series. (See Figure 4)

PHOTOMULTIPLIER TUBE R9779

Figure 1: Typical Spectral Response

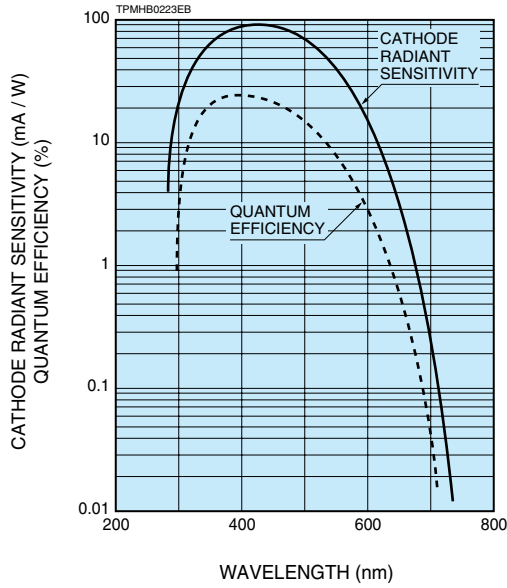


Figure 2: Typical Gain

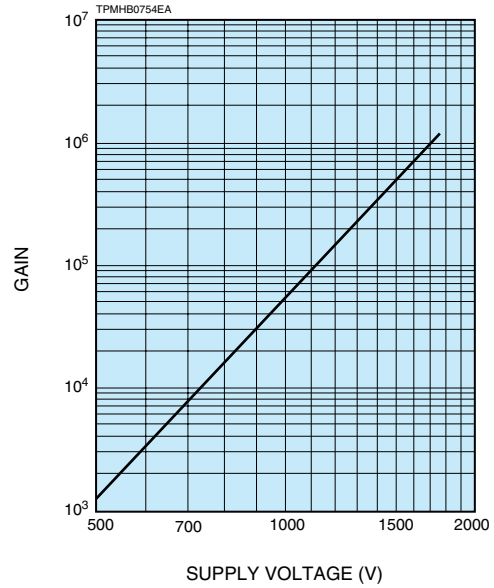
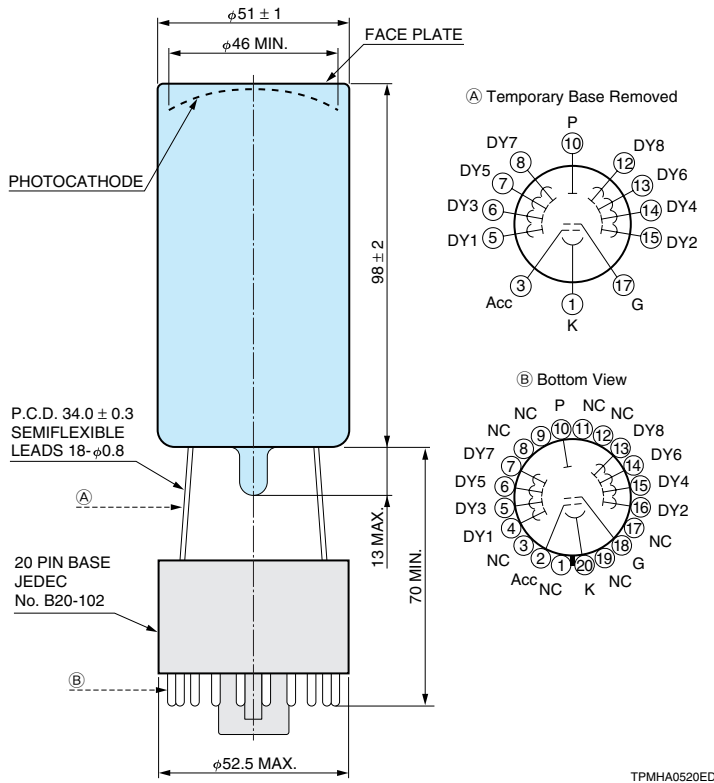
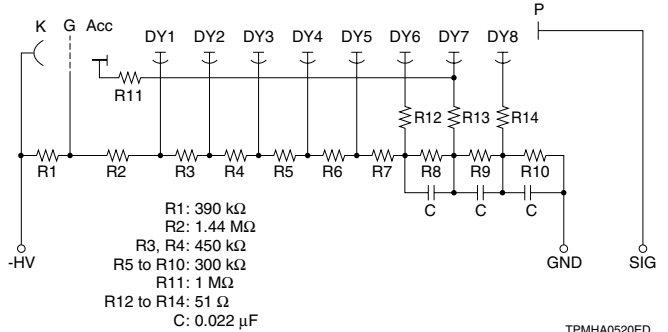


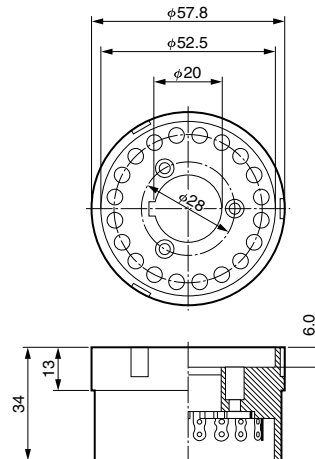
Figure 3: Dimensional Outline and Basing Diagram (Unit: mm)



Recommended Voltage Divider Circuit



Socket E678-20B (Supplied)



NOTES

The material in the R9779 contains beryllium. Please follow the applicable regulations regarding disposal of hazardous materials and industrial wastes in your country, state, region or province.

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